Pump coupling optimizied 3-wave-mixing Josephson parametric amplifier

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Three-wave mixing Josephson parametric amplifiers (JPAs) typically require pump that is 6 to 7 orders of magnitude stronger than the signal power it can handle. The leakage of pump towards signal circuitry is generally harmful in application. We would also like to bring power efficiency, defined as the ratio between maximum output power in linear amplification regime and pump power required, into future concern of the JPA community. We propose a JPA that minimizes pump leakage and at the same time maximizes the pump coupling efficiency. By applying on-chip microwave filtering on a 3-wave-mixing JPA whose pump is off-resonance, we engineer dual-band coupling networks which satisfy different conditions at signal frequency and pump frequency separately. We show experimentally that more than 20dB improvement in power efficiency and more than 20dB suppression of pump leakage can be achieved by the filtering technique, while maintaining dynamic range and near-quantum limited noise performance.

I. INTRODUCTION

(General background)

- (In JPA applications, minimum backaction is usually wanted)
- JPAs require strong pump to work
- Pump leakage are bad and need to be dealt with
- Geneneally, the higher power handling ability a JPA has, the stronger pump it requires:
 - 1. Might require extra efforts on pump isolation
 - 2. Concerning fridge cooling power, the pump power we can deliver could become a limiting factor

Josephson parametric amplifiers (JPAs) are commonly used in precision microwave measurements, such as superconducting qubit readout, microwave optomechanics experiment, electron spin resonance measurement, and Axion detection. Besides low added noise, usually minimum backaction is also wanted in such applications. All JPAs require rf pump that is orders of magnitude stronger than input signal. If not dealt with properly, JPA pump could harm the **system under measurement**. Usually external non-reciprocal components are employed to achieve directionality, as well as isolating the **system under measurement** from pump in amplifier circuitry.

Many recent researches are focused on improving dynamic range of JPAs. While JPAs with higher signal power handling ability generally need higher pump power, which might need extra efforts on pump isolation. In addition, concerning cooling power of dilution fridges, the maximum pump power we can deliver at the JPA could itself become a limiting factor.

(Detailed background about 3wm JPAs)

• Pump that is close to signal frequency is usually more harmful

- Compared to 4wm JPAs, 3wm JPAs has the advantage that they're pumped off-resonance
- However, pump being off-resonance makes it poorly coupled
- As a result, 3wm JPAs typically require larger pump power delivered (than 4wm JPAs) to work

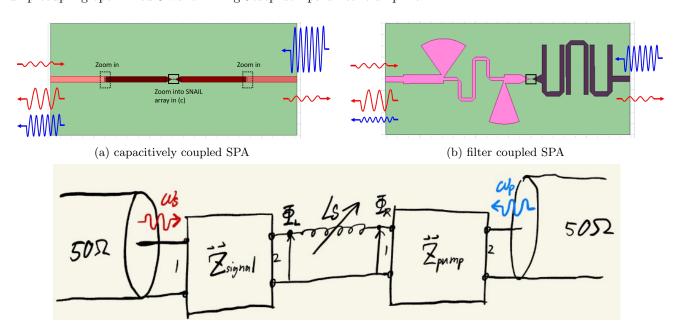
Resonance JPAs amplifies signal that is close to its resonance frequency ω_a . Therefore, presence of onresonance pump is usually more harmful, for the **systems under measurement** are typically more susceptible to noise near signal frequency. In this sense, the fact that a 3-wave-mixing JPA is pumped off-resonance is advantageous over 4-wave-mixing JPAs whose pump is on-resonance.

However, pump being detuned from the amplifier mode typically makes the pump poorly coupled to 3-wave-mixing JPAs. As a result, in order to achieve sufficient intra-device pump strenth to work, more pump power need to be delivered at 3-wave-mixing JPAs compared to that required for 4-wave-mixing JPAs.

(Intro of this paper)

- Propose a technique (filtering) that applies to 3wm JPAs to:
 - 1. Suppress pump leakage
 - 2. Enable efficient pumping
- From experimental comparison between a common two-port SPA and a **filter coupled SPA**, we show that the latter:
 - 1. Shows **dBm less pump leakage from signal port at 20dB gain working condition
 - 2. Require **dBm less pump power delivered at pump port to achieve **20dB low signal gain**

In this letter, we demonstrate a technique that applies to 3-wave-mixing JPAs to suppress pump leakage



(c) General circuit model: SPA with arbitrary linear network at both ports

FIG. 1: Layout of a capacitively coupled SPA and a filter coupled SPA. Reflection gain is obtained from signal port, and minimal signal leakage from pump port is expected. Originally, different coupling capacitors are employed at signal and pump port. We suggest that a bandstop filter (pink) at signal port can suppress pump leakage while maintaining moderate signal coupling. And a bandpass filter (purple) at pump port provide strong coupling for pump and weak coupling for signal.

towards qubit as well as enable efficient pumping. We present a 3-wave-mixing JPA that has two rf ports with on-chip microwave filtering. One port, which is referred to as signal port, provides reflection gain for input signal. The other port which I name pump port is for current pumping. We have shown that, compared to a similar device with traditional capacitively coupled ports??, the filter coupled SPA 1) shows 20dB less pump leakage from signal port, and 2) requires 20dB less pump power delivered at device pump port, when achieving the same amplification condition.

II. INTRODUCE DEVICE

- SPA: a degenerate JPA based on 3wm nonlinearity from SNAIL participation
- Having a separate pump port is favorable for qubit protection
- $\kappa^{(p)}[\omega_s]$ has to be small for noise property
- Pump power required to achieve 20dB gain:
 - 1. Gain depends on α_p
 - 2. α_p depends on pump power and pump port coupling $\kappa^{(p)}[\omega_p]$
- $\kappa^{(s)}[\omega_s]$ has to guarantee moderate bandwidth

- $\kappa^{(s)}[\omega_p]$ and α_p determines pump leakage
- Frequency separation between signal and pump allows for engineering different $\kappa[\omega_s]$ and $\kappa[\omega_p]$

The device in this work is a SNAIL parametric amplifier (SPA)?, by which we refer to a degenerate parametric amplifier formed by a resonance mode with Superconducting Nonlinear Asymmetric Inductive eLement (SNAIL)? participation.

A traditional SPA?? is formed by an array of SNAILs sitting at the center of a $\lambda/2$ microstrip resonantor, as shown in Figure.3 (a). An SPA has Hamiltonian with third and fourth order nonlinearity:

$$H_{\text{SPA}} = \hbar \omega_a a^{\dagger} a + g_3 (a^{\dagger} + a)^3 + g_4 (a^{\dagger} + a)^4$$
 (1)

Upon pumping at frequency $\omega_p \approx 2\omega_a$, Quantum Langevin Equation (QLE) gives phase preserving power gain:

$$G = 1 + \frac{4\kappa^2 |g|^2}{\left(\Delta^2 + \frac{\kappa^2}{2} - 4|g|^2\right)^2}$$
 (2)

for signal frequency $\omega_s \approx \omega_p/2$ and low signal power, where $g=2g_3\alpha_p$ with α_p being mean-field intra-device pump amplitude, and $\Delta=\omega_a+\left(\frac{32}{3}g_4-28\frac{g_3^2}{\omega_a}\right)\left|\alpha_p\right|^2-\frac{\omega_p}{2}$

is detuning between $\omega_p/2$ and Stark-shifted mode frequency due to α_p .

Although it's possible to apply current pumping from the same port as signal, having a separate port for pump is favored as it removed the necessity of directional couplers or multiplexers in front of signal port. And more importantly, reflected power due to pump port mismatch doesnt see the qubit circuitry, which greatly eases pump isolation.

In this case, signal leakage from pump port has to be minimized to guarantee near-quantum-limited noise performance. Thus the pump port in Figure.3 (a) is weakly coupled which, on the other hand, makes pump coupling rate badly low and worsens the pump power inefficiency problem of 3-wave-mixing JPAs.

Signal port coupling capacitor is typically made to achieve coupling rate $\kappa/2\pi$ on the order of 100 MHz. While intra-mode pump also leaks into signal line via this coupling capacitor, yet no previous work has been focused on reducing pump leakage.

Pump leakage due to signal port coupling and pump in efficiency due to pump port coupling can be addressed with the same idea of microwave filtering. The frequency separation between signal and pump in 3-wave-mixing JPAs can be utilized, enabling significantly different coupling rate at ω_s and ω_p .

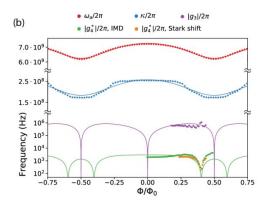


FIG. 2: Flux sweep showing frequency, kappa, g3 and g4 (this is from Vlad's paper)

III. MODEL

- A resonance mode at ω_a with SNAIL participation has to be guaranteed by the phase condition
- Requirement: $\operatorname{Im} Z^{(s)}[\omega_a] + \operatorname{Im} Z^{(p)}[\omega_a] = -\omega_a L_S$
- Defined coupling rate $\kappa/2$: $\operatorname{Re} Z^{(s/p)}[\omega] = \frac{\kappa^{(s/p)}[\omega]}{2} L_S$
- Introduce energy participation in SNAIL (in later sections, two devices with similar SNAIL participation are compared)

• The filter coupled SPA has similar κ , g_3 and g_4 as the capacitively coupled one. (Should I include a figure like Figure.2 showing that?)

IV. DATA

(About pump leakage)

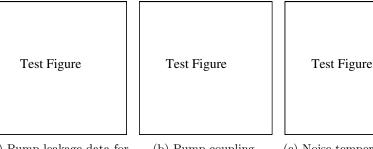
- Power leakage at ω_p under 20dB gain condition is suppressed by **dBm by the filter
- If stiff pump approximation holds, this power should equal S12 * pump power applied at pump port
- (Do we have any conclusion on pump leakage's influence on qubit? e.g. related to thermal population?)

(About pump coupling efficiency)

- Relate α_p to Φ_{ω_p} across SNAILs
- α_p^2 is proportional to pump power, the coefficient determined by linear coupling networks
- In order to achieve 20dB gain, the filter coupled device require **dBm less power deliver at device pump port than the capacitively coupled one.

V. POWER EFFICIENCY AND NOISE

- Define power efficiency as the ratio between maximum output power (Gain * P1dB) and pump power delivered
- Comment on the fact that JPAs with higher P1dB generally need larger α_p
- Only noise at ω_s matters. Therefore, for pump line, we don't even need any attenuation on base plate, but filter instead.
- Data shows that manually added ω_p noise that amount to 4K power doesn't change NVR. (should we have a figure for this?)
- (Is there some more general link between added noise and power efficiency? Compare JPA to the DC powered transistor amplifers)



(a) Pump leakage data for two devices. Each includes traces: 1. Pump leakage at 20dB gain condition measured from spectrum analyzer 2. S12 (measured at low power) * pump power applied at pump port 3. Theory using estimate α_p and simulated $\kappa^{(s)}[\omega_p]$

(b) Pump coupling efficiency data for two devices. α_p versus power delivered at pump port. (Under 10dB and 20dB gain respectively.)

(c) Noise temperature of two devices.

FIG. 3: Data points aguired at different flux points.

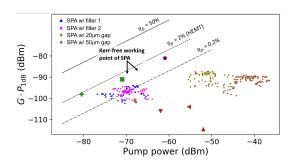


FIG. 4: Power efficiency

Appendix A: Pumpistor model for current pumped SNAIL array

(The original pumpistor model deals with flux pumped SQUID. The result I want to draw from this model is to model the current pumped SNAIL array as a inductance in parallel with a negative resistance, which would be handy in next chapter.)

SNAIL potential expansion:

$$U_S = E_J \left(c_0 + \frac{c_2}{2!} \tilde{\varphi}^2 + \frac{c_3}{3!} \tilde{\varphi}^3 + \frac{c_4}{4!} \tilde{\varphi}^4 + \cdots \right)$$
 (A1)

where $\tilde{\varphi} = \frac{\Phi_L - \Phi_R}{M\phi_0} - \varphi_{\min}$, is phase difference across each SNAIL expanded around the static minimum φ_{\min} determined by external flux bias.

$$I(t) = \frac{E_J}{\phi_0} \left(c_2 \tilde{\varphi} + \frac{c_3}{2} \tilde{\varphi}^2 + \frac{c_4}{6} \tilde{\varphi}^3 + \cdots \right) \tag{A2}$$

In phase preserving amplification process, the frequencies of interest are ω_s , ω_p and $-\omega_i$, with $\omega_i = \omega_p - \omega_s$.

Using phasor representation, we write:

$$\tilde{\varphi}(t) = \operatorname{Re}\left(\varphi_{\omega_s} e^{j\omega_s t} + \varphi_{\omega_p} e^{j\omega_p t} + \varphi_{\omega_i}^* e^{-j\omega_i t}\right)$$
 (A3)

(where $\varphi_{\omega_i}^*$ is the "counter-rotating" amplitude at idler frequency)

and similarly

$$I(t) = \operatorname{Re} \left(I_{\omega_s} \mathrm{e}^{j\omega_s t} + I_{\omega_p} \mathrm{e}^{j\omega_p t} + I_{\omega_i}^* \mathrm{e}^{-j\omega_i t} \right)$$

Consider the 3-wave-mixing term in equation (A2), the $e^{j\omega_s t}$ harmonic component of I(t) will yield:

$$I_{\omega_s} = I_c(c_2\varphi_{\omega_s} + c_3\varphi_{\omega_n}\varphi_{\omega_s}^*)$$

here $I_c = E_J/\phi_0$, is critical current of large junction in SNAIL. Since voltage across SNAIL array is given by $V(t) = M\phi_0\dot{\varphi}(t)$, which has $e^{j\omega_s t}$ harmonic component:

$$V_{\omega_s} = j\omega_s M \phi_0 \varphi_{\omega_s} \tag{A4}$$

admittance of the SNAIL array at ω_s will be given by:

$$Y_{S} = \frac{I_{\omega_{s}}}{V_{\omega_{s}}}$$

$$= \frac{c_{2}}{i\omega_{s}ML_{I}} + \frac{c_{3}\frac{\varphi_{\omega_{p}}\varphi_{\omega_{i}}^{*}}{\varphi_{\omega_{s}}}}{i\omega_{s}ML_{I}}$$
(A5)

 $(L_J = \phi_0/I_c \text{ is Josephson inductance of the large junction in SNAIL.)}$

Therefore, it acts like two elements in parallel. The first term correspond to the linear inductance $L_S=ML_J/c_2$ of the SNAIL array. The second term, which is called a "pumpistor", could be reactive or resistive, depending on the phase condition between φ_{ω_p} , φ_{ω_s} and $\varphi_{\omega_i}^*$. In the case of linear amplification, the pumpistor serves as a negative resistance.

Under high gain approximation, where $|\varphi_{\omega_s}| = |\varphi_{\omega_i}|$, the resistance will have value:

$$|R| = \frac{c_3}{\omega_s M L_J} |\varphi_{\omega_p}| \tag{A6}$$

which, under stiff pump approximation, is fully determined by the pump strength at ω_p frequency. Therefore the pumpistor is a linear element in circuit analysis at signal frequency (i.e. in Figure.6 in next section).

(This is the whole point of pumpistor model, to linearize the nonlinear effect.)

However, to evaluate the exact φ_{ω_p} value we use (usually to get 20dB gain), some self-consistent equations need to be solved.

Making use of equation (A4) and the $e^{-j\omega_s t}$ harmonic component:

$$V_{\omega_i}^* = -j\omega_i M \phi_0 \varphi_{\omega_i}^* \tag{A7}$$

let's rewrite

$$\begin{split} \frac{c_3 \frac{\varphi_{\omega_p} \varphi_{\omega_i}^*}{\varphi_{\omega_s}}}{j\omega_s M L_J} V_{\omega_s} &= \frac{c_2}{M L_J} \frac{c_3 \varphi_{\omega_p}}{c_2} \frac{V_{\omega_s}}{j\omega_s \varphi_{\omega_s}} \varphi_{\omega_i}^* \\ &= \frac{c_2}{M L_J} \frac{c_3 \varphi_{\omega_p}}{c_2} \frac{V_{\omega_i}^*}{-j\omega_i} \end{split}$$

We can name $\epsilon = \frac{c_3 \varphi_{\omega_p}}{c_2}$. Combining with a similar current-voltage relation at $-\omega_i$, we get the linearized response of SNAIL array to signal and idler voltage:

$$\begin{pmatrix}
I_{\omega_s} \\
I_{\omega_i}^*
\end{pmatrix} = \frac{1}{jL_S} \begin{pmatrix}
\frac{1}{\omega_s} & \frac{-\epsilon}{\omega_i} \\
\frac{\epsilon^*}{\omega_s} & \frac{-1}{\omega_i}
\end{pmatrix} \begin{pmatrix}
V_{\omega_s} \\
V_{\omega_i}^*
\end{pmatrix}$$
(A8)

which should be put together with other linear elements in the circuit (see equation (B4) in next section) and solved self-consistently.

Comment:

*Input impedance of the external linear network seen by the SNAIL array will be the same at ω_s and ω_i (assume small signal detuning). Combining equation (A8) and response from external networks (forms a mode), we can calculate what φ_{ω_p} should be to achieve 20dB gain. That's all we need to get the effective negative resistance of the pumpistor.

And then, section C is about how to calculate voltage required at pump port to achieve the amount of φ_{ω_p} across SNAIL array, and pump leakage from signal port.

**In addition, if Kerr effect is considered, c_4 terms should be kept and diagonal elements in equation (A8) will be shifted due to $|\epsilon|^2$ (contributes from $|\varphi_{\omega_p}|^2$), and $|V_{\omega_s}|^2$ and $|V_{\omega_i}|^2$. The latter two are to be solved self-consistently. While $|\epsilon|^2$, under stiff pump approximation, is assumed constant,

Appendix B: Input impedance required for SPA mode

From Thevenin theorem, any one-port (i.e. two-terminal) linear network along with sinusoidal sources can be modeled as a simple voltage source in series with input impedance seen from the port. In SPA case, we would have a ω_s tone driving signal port, and a ω_p tone driving pump port. Thus the equivalent circuit should look like Figure.5.

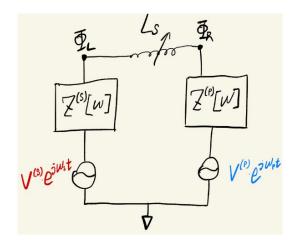


FIG. 5: The venin equivalent circuit

(Note that the relation between Thevenin voltage source $V^{(s/p)}$ and actual voltage at end of transmission line has to be simulated as well.)

For resonance parametric amplification, besides the pumpistor (acting like a negative resistance), we also need a mode around signal frequency. This section discusses how to guarantee a mode with well-defined frequency and SNAIL participation when designing external coupling network.

When talking about resonance condition, let's first keep only the linear part of equation (A2):

$$I(t) = I_c c_2 \tilde{\varphi} = \frac{\Phi_L(t) - \Phi_R(t)}{L_S} - M\phi_0 \varphi_{\min}/L_S \quad (B1)$$

At the same time, the signal port network can be characterized by input admittance $Y^{(s)}$ (with the other port 50 Ω loaded), resulting in linear response between current I and node voltage $V_L = \dot{\Phi}_L$:

$$-I(t) = \int Y^{(s)}(t-\tau)\dot{\Phi}_L(\tau) d\tau$$
 (B2)

and similarly for the right hand side:

$$I(t) = \int Y^{(p)}(t-\tau)\dot{\Phi}_R(\tau) d\tau$$
 (B3)

Laplace transform on equation (B2) and B3, as well as

equation (B1), we get:

$$I[s] = -s\Phi_L[s]Y^{(s)}[s]$$

$$= s\Phi_R[s]Y^{(p)}[s]$$

$$= \frac{\Phi_L[s] - \Phi_R[s]}{L_S}$$
(B4)

or written equivalently:

$$\begin{pmatrix} 1 & sY^{(s)} & 0 \\ 1 & 0 & -sY^{(p)} \\ 1 & -1/L_S & 1/L_S \end{pmatrix} \begin{pmatrix} I \\ \Phi_L \\ \Phi_R \end{pmatrix} = 0$$
 (B5)

Existance of non-trivial solutions requires:

$$\frac{1}{Y^{(s)}[s]} + \frac{1}{Y^{(p)}[s]} = -sL_S$$
 (B6)

If we write $s = -\kappa/2 + j\omega$ and express the linear response in input impedance instead of input admittance:

$$\operatorname{Im} Z^{(s)}[-\kappa/2 + j\omega] + \operatorname{Im} Z^{(p)}[-\kappa/2 + j\omega] = -\omega L_S$$
(B7)

$$\operatorname{Re}Z^{(s)}[-\kappa/2+j\omega] + \operatorname{Re}Z^{(p)}[-\kappa/2+j\omega] = \frac{\kappa}{2}L_S$$
 (B8)

Assuming a set of $\{\omega_k\}$ and $\{\kappa_k\}$ that satisfy these conditions, solution to the system will be in the form of linear combination of eigenmodes:

$$I(t) = \sum_{k} I_{\omega_k} e^{-\frac{\kappa_k}{2}t} e^{j\omega_k t}$$
 (B9)

with ω_k being frequency of the k-th eigenmode, and $\kappa_k/2$ being amplitude damping rate of that mode (because we usually define κ as energy damping rate).

To design an SPA mode with arbitrary coupling networks, imaginary (reactive) parts of input impedance $Z^{(s)}$ and $Z^{(p)}$ has to satisfy requirement B7 at desired mode frequency ω_a . And reasonable κ for this mode has to be achieved by real part of $Z^{(s)}$ (since $\text{Re}Z^{(p)}$ should be close to 0 to prevent signal leakage from pump port). Note that SNAIL expansion parameter c_2 is dependent on external flux bias. As L_S varies with flux, so does the ω that satisfies equation (B7), thus tunes the mode frequency. For degenerate amplification, no other modes should exist within the frequency range of interest.

(Extract SNAIL inductance participation from slope of imaginary part of input impedance)

We can generally define total admittance of the loop $Y_{\text{sys}}[\omega] = \left(Z^{(s)}[\omega] + Z^{(p)}[\omega] + j\omega L_S\right)^{-1}$.

Here I propose an easy way to do so by extracting SNAIL **inductance participation** in the mode.

The assumption I make is that behaviour of $Y_{\rm sys}[\omega]$ near ω_a (for whatever frequency my signal could lie) can be modeled for by a simple RLC.

The signal Thevenin voltage source $V^{(s)}$ sees the whole system as $Y_{\text{sys}}[\omega_s]$, that responds exactly the same (for near resonance ω_s) as a series RLC.

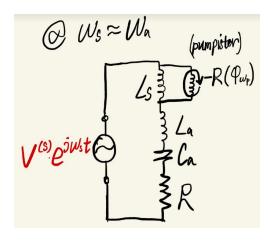


FIG. 6: Approximate circuit at $\omega_s \approx \omega_a$

The RLC model should account for the mode frequency ω_a , residual of $\mathrm{Im}Y_{\mathrm{sys}}$ at ω_a , and energy damping rate κ of the mode. (To account for amplification, we should put a pumpistor in parallel with L_S .)

**How this model helps:

Using this model, we can calculate equivalent L_a and C_a from the values and slopes of imaginary part of the two input impedances (from linear simulation). All later nonlinearity calculation can be easily done analytically, and all existing results from mode amplitude a and a^{\dagger} language applies directly. Doesn't involve the simulated $Z[\omega]$ function in calculation, and doesn't need harmonic balance simulation.

Note that 4-th and higher orders nonlinearity calculated from this circuit are different from Foster circuit BBQ. Following the current conservation argument in Appendix A of?, we have to treat the nonlinear inductance in series with linear inductance, unlike in Foster circuit BBQ where nonlinearity is treated in parallel with linear part. Another way to interprate the reason why Foster BBQ break down for SPA is that SNAIL participation in higher modes are non-negligible, therefore renormalization from higher modes has to be accounted for.

Appendix C: Calculation: two-port SPA pump leakage

..... Easy part, just get the relation between φ_{ω_p} and $V^{(p)}$, calculate how much power at end of pump port transmission line gives φ_{ω_p} we need.

And convert (using signal port network simulation result) the current I_{ω_p} into power seen by signal port transmission line.

I've assumed stiff pump, which means I didn't do full harmonic balance. Which is doable though, by writing the equation (A8) like relation at ω_p also, and solving the three self-consistently. (This will allow us to characterize pump depletion. But I personally don't want to do it this way. Filters have kind of complicated response over pump frequency range, and we'll have to use sim-

ulated $Z^{(p)}[\omega]$ in all calculations. That could result in less robustness in simulation result and larger deviation

between simulation and experiment. Also, I think this is not directly related to the main point of this paper.)